## MAAM02350-A2



# Wide Band GaAs MMIC Amplifier 0.2 - 3.0 GHz

Rev. V3

#### **Features**

High Gain: 18 dB

Output Power: +14 dBm

Noise Figure: 4 dBSingle Supply: +6 V

Gain Flatness: ± 0.75 dB

Lead-Free 8-lead Ceramic Package

• RoHS\* Compliant and 260°C Reflow Compatible

#### **Description**

M/A-COM's MAAM02350-A2 is a wide band, MMIC amplifier housed in a small, lead-free, 8-lead ceramic package. It includes two integrated gain stages and employs resistive feedback to obtain flat gain and a good, 50-ohm, input and output impedance match over a very wide bandwidth. The MAAM02350-A2 operates from a single +6 V supply. It is monolithic, requiring only DC blocking capacitors, no other external components are needed.

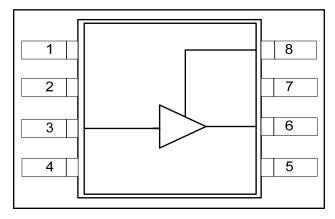
The MAAM02350-A2 functions well as a generic IF, driver or buffer amplifier where high gain, low noise figure, excellent linearity and low power consumption are important. Because of its wide bandwidth, the MAAM02350-A2 can be used in numerous commercial and government system applications, such as wireless communications, EW and radar.

The MAAM02350-A2 is manufactured in-house using a reliable, 0.5-micron, GaAs MESFET process. This product is 100% RF tested to ensure compliance to performance specifications.

#### **Ordering Information**

Part Number	Package		
MAAM02350-A2	8-Lead Ceramic (CR-3)		
MAAM02350-A2G	Gull Wing (CR-10)		

#### **Functional Schematic**



### Pin Configuration<sup>1</sup>

Pin No.	Function	Pin No.	Function
1	Ground	5	Ground
2	Ground	6	RF Output
3	RF Input	7	Ground
4	Ground	8	$V_{DD}$

The package bottom must be connected to RF and DC ground.

## Absolute Maximum Ratings <sup>2,3</sup>

Parameter	Absolute Maximum		
$V_{DD}$	+10 V		
Input Power	+20 dBm		
Current	150 mA		
Channel Temperature <sup>4</sup>	+150°C		
Operating Temperature	-55°C to +100°C		
Storage Temperature	-65°C to +150°C		

- 2. Exceeding any one or combination of these limits may cause permanent damage to this device.
- M/A-COM does not recommend sustained operation near these survivability limits.
- 4. Typical thermal resistance ( $\Theta_{ic}$ ) = +80°C/W

North Americ
 Europe Tel:

• North America Tel: 800.366.2266 / Fax: 978.366.2266

• Europe Tel: 44.1908.574.200 / Fax: 44.1908.574.300

Asia/Pacific Tel: 81.44.844.8296 / Fax: 81.44.844.8298
 Visit www.macomtech.com for additional data sheets and product information.

M/A-COM Technology Solutions Inc. and its affiliates reserve the right to make changes to the product(s) or information contained herein without notice.

<sup>\*</sup> Restrictions on Hazardous Substances, European Union Directive 2002/95/EC.



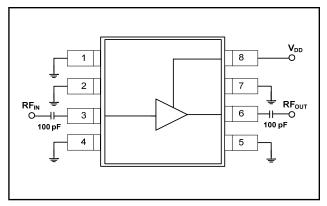
## Wide Band GaAs MMIC Amplifier 0.2 - 3.0 GHz

Rev. V3

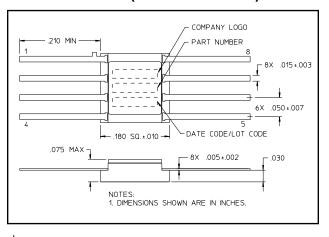
### Electrical Specifications: $T_A = 25$ °C, $V_{DD} = +6$ V, $Z_0 = 50$ $\Omega$

Parameter	Test Conditions	Units	Min.	Тур.	Max.
Gain	$0.2 - 3.0 \text{ GHz}, P_{IN} = -30 \text{ dBm}$	dB	16	18	_
Noise Figure	0.2 - 3.0 GHz	dB	_	4.0	4.5
Gain Flatness	$0.2 - 3.0 \text{ GHz}, P_{\text{IN}} = -30 \text{ dBm}$	dB	_	± 0.5	_
Input VSWR	$0.2 - 3.0 \text{ GHz}, P_{\text{IN}} = -30 \text{ dBm}$	Ratio	_	1.7:1	_
Output VSWR	0.2 - 3.0 GHz, P <sub>IN</sub> = -30 dBm	Ratio	_	1.3:1	_
Output 1 dB Compression	0.2 - 3.0 GHz	dBm	_	+14	_
Input IP3	$0.2 - 3.0 \text{ GHz}, P_{\text{IN}} = -30 \text{ dBm}$	dBm	_	+6	_
Reverse Isolation	0.2 - 3.0 GHz, P <sub>IN</sub> = -30 dBm	dB	_	30	_
Bias Current	_	mA	_	65	100

#### **Application Schematic**



## Lead-Free CR-3 (MAAM02350-A2)<sup>†</sup>



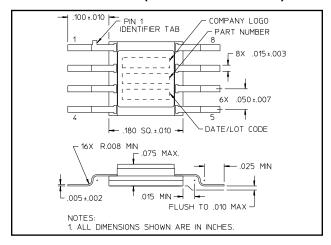
#### **Handling Procedures**

Please observe the following precautions to avoid damage:

#### **Static Sensitivity**

Gallium Arsenide Integrated Circuits are sensitive to electrostatic discharge (ESD) and can be damaged by static electricity. Proper ESD control techniques should be used when handling these devices.

## Lead-Free CR-10 (MAAM02350-A2G)<sup>†</sup>



<sup>&</sup>lt;sup>†</sup> Reference Application Note M538 for lead-free solder reflow recommendations. Meets JEDEC moisture sensitivity level 1 requirements.

- ADVANCED: Data Sheets contain information regarding a product M/A-COM Technology Solutions is considering for development. Performance is based on target specifications, simulated results, and/or prototype measurements. Commitment to develop is not guaranteed.

  PRELIMINARY: Data Sheets contain information regarding a product M/A-COM Technology Solutions has under development. Performance is based on engineering tests. Specifications are typical. Mechanical outline has been fixed. Engineering samples and/or test data may be available. Commitment to produce in volume is not guaranteed.
- North America Tel: 800.366.2266 / Fax: 978.366.2266
- Europe Tel: 44.1908.574.200 / Fax: 44.1908.574.300
- Asia/Pacific Tel: 81.44.844.8296 / Fax: 81.44.844.8298
   Visit www.macomtech.com for additional data sheets and product information.

M/A-COM Technology Solutions Inc. and its affiliates reserve the right to make changes to the product(s) or information contained herein without notice.

2

## MAAM02350-A2

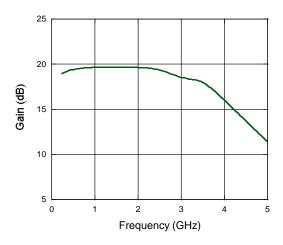


# Wide Band GaAs MMIC Amplifier 0.2 - 3.0 GHz

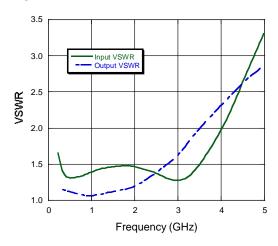
Rev. V3

### Typical Performance @ +25°C

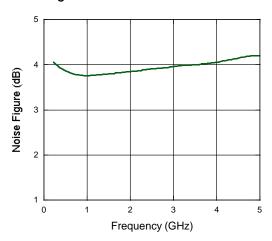
#### Gain



#### **VSWR**



#### Noise Figure



M/A-COM Technology Solutions Inc. and its affiliates reserve the right to make changes to the product(s) or information contained herein without notice.

<sup>•</sup> North America Tel: 800.366.2266 / Fax: 978.366.2266

<sup>•</sup> Europe Tel: 44.1908.574.200 / Fax: 44.1908.574.300

Asia/Pacific Tel: 81.44.844.8296 / Fax: 81.44.844.8298
 Visit www.macomtech.com for additional data sheets and product information.